Low-power configurable gate with voltage-level translator Rev. 2 — 5 October 2018 Product data sheet

1. General description

The 74AUP1T98-Q100 provides low-power, low-voltage configurable logic gate functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter and buffer. All inputs can be connected to V_{CC} or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 2.3 V to 3.6 V.

The 74AUP1T98-Q100 is designed for logic-level translation applications with input switching levels that accept 1.8 V low-voltage CMOS signals, while operating from either a single 2.5 V or 3.3 V supply voltage.

The wide supply voltage range ensures normal operation as battery voltage drops from 3.6 V to 2.3 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger inputs make the circuit tolerant to slower input rise and fall times across the entire V_{CC} range.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A, exceeds 5000 V
 - HBM JESD22-A114F Class 3A, exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Low static power consumption; I_{CC} = 1.5 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation

3. Ordering information

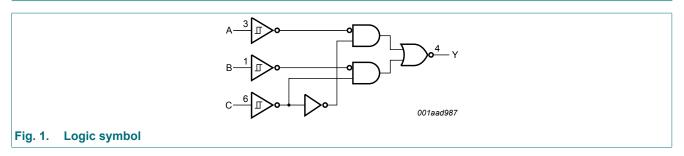
Table 1. Ordering information							
Type number Package							
	Temperature range Name Description Version						
74AUP1T98GW-Q100	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363			

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4. Marking

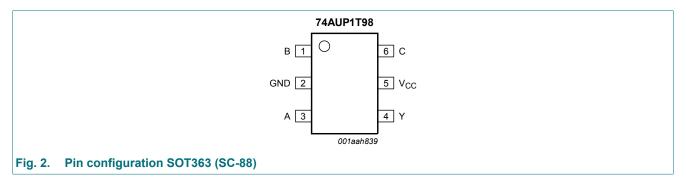
Table 2. Marking	
Type number	Marking code
74AUP1T98GW-Q100	aR

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Y	4	data output
V _{CC}	5	supply voltage
С	6	data input

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input C			Output
C	В	A	Y
L	L	L	Н
L	L	Н	Н
L	Н	L	L
L	Н	Н	L
Н	L	L	Н
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	L

7.1. Logic configurations

Logic function	Figure
2-input MUX (inverting)	see Fig. 3
2-input NAND	see Fig. 4
2-input NOR with one input inverted	see Fig. 5
2-input AND with one input inverted	see Fig. 5
2-input NAND with one input inverted	see Fig. 6
2-input OR with one input inverted	see Fig. 6
2-input NOR	see Fig. 7
Buffer	see Fig. 8
Inverter	see Fig. 9

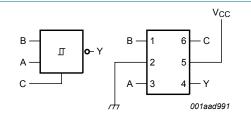
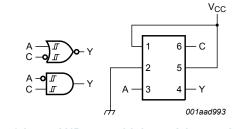
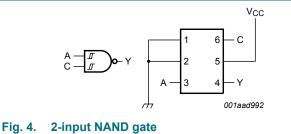


Fig. 3. 2-input MUX (inverting)







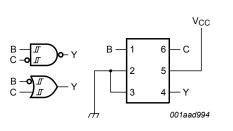
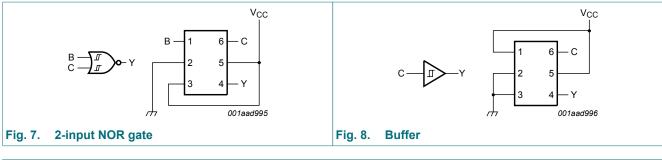
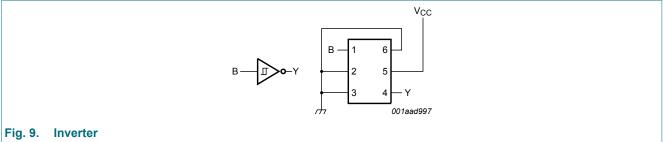


Fig. 6. 2-input OR gate with input B inverted or 2-input NAND gate with input C inverted

Low-power configurable gate with voltage-level translator





8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V ₀ < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V_{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{T+}	positive-going threshold	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.16	V
V _{T-}	negative-going threshold	V _{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
voltage	voltage	V _{CC} = 3.0 V to 3.6 V	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.23	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.25	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = -20 µA; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = 20 µA; V_{CC} = 2.3 V to 3.6 V	-	-	0.10	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.1	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_0 = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.2	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF

Low-power configurable	gate with	voltage-level	translator
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	40 °C to +85 °C					_
V _{T+}	positive-going threshold	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.19	V
V _{T-}	negative-going threshold	V _{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.50	-	0.85	V
V _H I	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.15	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = -20 µA; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = 20 µA; V_{CC} = 2.3 V to 3.6 V	-	-	0.1	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A}; V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.5	μA
Δl _{CC}	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}; I_{O} = 0 \text{ A}$ [1]	-	-	4	μA
		$V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V; } I_{\rm O} = 0 \text{ A}$ [2]	-	-	12	μA

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	40 °C to +125 °C				I	
V _{T+}	positive-going threshold	V_{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.19	V
V _{T-}	negative-going threshold	V_{CC} = 2.3 V to 2.7 V	0.33	-	0.64	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.46	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.15	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = -20 µA; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = 20 µA; V_{CC} = 2.3 V to 3.6 V	-	-	0.11	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
∆I _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 2.3 V to 3.6 V	-	-	3.5	μA
∆l _{CC}	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$ [1]	-	-	7	μA
		$V_{\rm CC}$ = 3.0 V to 3.6 V; I _O = 0 A [2]	-	-	22	μA

[1] [2]

One input at 0.3 V or 1.1 V, other input at V_{CC} or GND. One input at 0.45 V or 1.2 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 11.

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit	
				Min	Typ [1]	Мах	Min	Max (85 °C)	Max (125 °C)	
V _{CC} = 2.3	3 V to 2.7 V; V _I = 1.6	65 V to 1.95 V								
t _{pd}	propagation delay	A, B, C to Y; see Fig. 10	[2]							
		C _L = 5 pF		2.0	3.6	5.7	0.5	6.8	7.5	ns
		C _L = 10 pF		2.5	4.2	6.3	1.0	7.9	8.7	ns
		C _L = 15 pF		2.9	4.6	6.9	1.0	8.7	9.6	ns
		C _L = 30 pF		3.9	5.8	8.3	1.5	10.8	11.9	ns
V _{CC} = 2.3	3 V to 2.7 V; V _I = 2.3	3 V to 2.7 V			· · · · ·		1	1		
t _{pd}	propagation delay	A, B, C to Y; see Fig. 10	[2]							
		C _L = 5 pF		1.7	3.4	5.6	0.5	6.0	6.6	ns
		C _L = 10 pF		2.1	4.0	6.3	1.0	7.1	7.9	ns
		C _L = 15 pF		2.5	4.5	6.9	1.0	7.9	8.7	ns
		C _L = 30 pF		3.4	5.6	8.4	1.5	10.0	11.0	ns
V _{CC} = 2.3	3 V to 2.7 V; V _I = 3.0) V to 3.6 V					1			
t _{pd}	propagation delay	A, B, C to Y; see Fig. 10	[2]							
		C _L = 5 pF		1.3	3.2	5.2	0.5	5.5	6.1	ns
		C _L = 10 pF		1.8	3.7	5.9	1.0	6.5	7.2	ns
		C _L = 15 pF		2.2	4.2	6.5	1.0	7.4	8.2	ns
		C _L = 30 pF		3.1	5.4	7.9	1.5	9.5	10.5	ns
V _{CC} = 3.	0 V to 3.6 V; V _I = 1.6	65 V to 1.95 V								
t _{pd}	propagation delay	A, B, C to Y; see Fig. 10	[2]							
		C _L = 5 pF		2.0	2.9	4.1	0.5	8.0	8.8	ns
		C _L = 10 pF		2.4	3.5	4.8	1.0	8.5	9.4	ns
		C _L = 15 pF		2.8	3.9	5.4	1.0	9.1	10.1	ns
		C _L = 30 pF		3.6	5.1	6.9	1.5	9.8	10.8	ns
V _{CC} = 3.	0 V to 3.6 V; V _I = 2.3	3 V to 2.7 V			· · · · ·		1			
t _{pd}	propagation delay	A, B, C to Y; see Fig. 10	[2]							
		C _L = 5 pF		1.5	2.8	4.4	0.5	5.3	5.9	ns
		C _L = 10 pF		2.0	3.4	5.1	1.0	6.1	6.8	ns
		C _L = 15 pF		2.4	3.9	5.7	1.0	6.8	7.5	ns
		C _L = 30 pF		3.4	5.0	7.2	1.5	8.5	9.4	ns
V _{CC} = 3.	0 V to 3.6 V; V _I = 3.0) V to 3.6 V					1		I	1
t _{pd}	propagation delay	A, B, C to Y; see <u>Fig. 10</u>	[2]							
		C _L = 5 pF		1.3	2.8	4.4	0.5	4.7	5.2	ns
		C _L = 10 pF		1.7	3.3	5.2	1.0	5.7	6.3	ns
		C _L = 15 pF		2.1	3.8	5.8	1.0	6.2	6.9	ns
		C _L = 30 pF		3.1	5.0	7.2	1.5	7.8	8.6	ns

Low-power configurable gate with voltage-level translator

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Тур [1]	Мах	Min	Max (85 °C)	Max (125 °C)	
T _{amb} = 2	5 °C								
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]							
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.3	-	-	-	-	pF

All typical values are measured at nominal V_{CC}. [1]

[2]

 t_{pd} is the same as t_{PLH} and t_{PHL} C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). [3]

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

11.1. Waveforms and test circuits

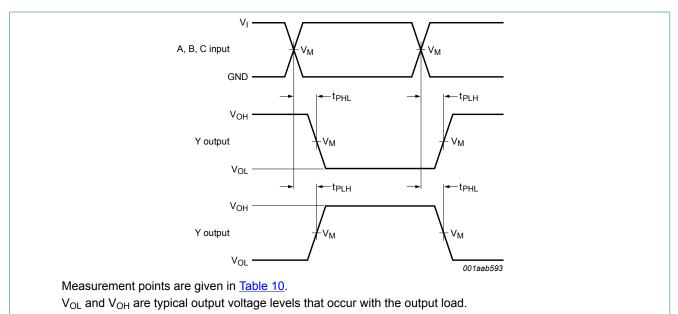


Fig. 10. Input A, B and C to output Y propagation delay times

Table 10. Measurement points

Supply voltage	Output	Input				
V _{cc}	V _M	V _M	VI	t _r = t _f		
2.3 V to 3.6 V	0.5 x V _{CC}	0.5 x V _I	1.65 V to 3.6 V	≤ 3.0 ns		

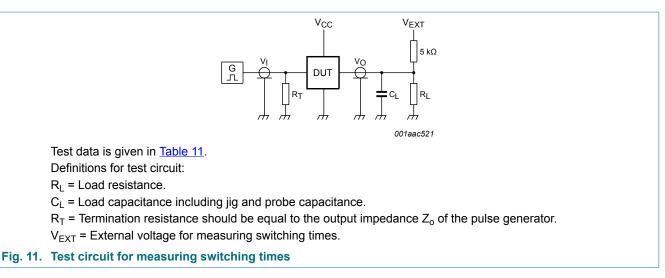


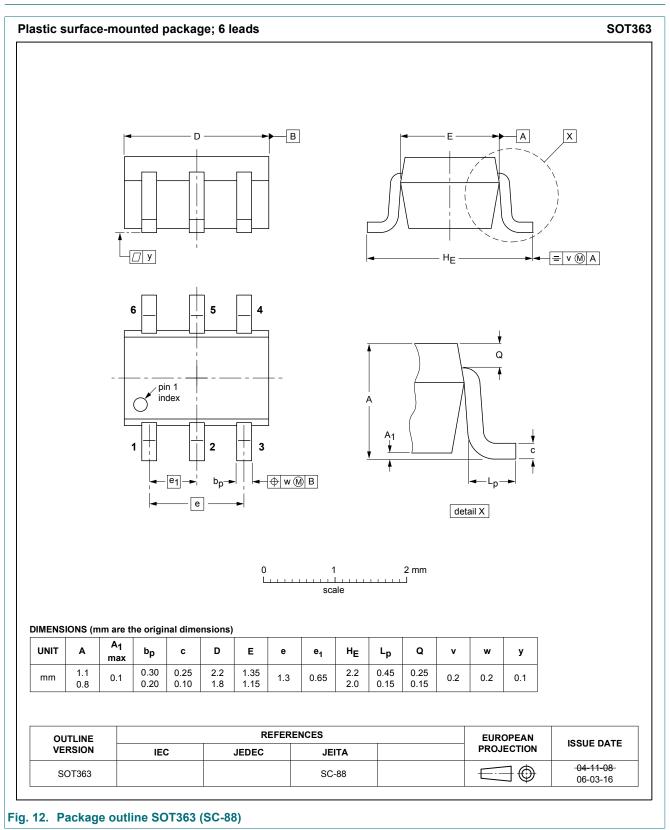
Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12. Package outline



13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T98_Q100 v.2	20181005	Product data sheet	-	74AUP1T98_Q100 v.1
Modifications:	Nexperia.	ita sheet has been redes		
74AUP1T98_Q100 v.1	20140519	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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